Configurable Multifunction Gate

The NLX1G97 MiniGate $^{\mathbb{M}}$ is an advanced high-speed CMOS multifunction gate. The device allows the user to choose logic functions MUX, AND, OR, NAND, NOR, INVERT and BUFFER. The device has Schmitt-trigger inputs, thereby enhancing noise immunity.

The NLX1G97 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

Features

- High Speed: $t_{PD} = 3.3 \text{ ns (Typ)} @ V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation: $I_{CC} = 1 \mu A$ (Maximum) at $T_A = 25^{\circ}C$
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb-Free Devices



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MARKING DIAGRAMS



ULLGA6 1.0 x 1.0 CASE 613AD





ULLGA6 1.2 x 1.0 CASE 613AE



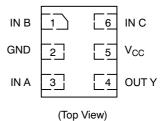


ULLGA6 1.45 x 1.0 CASE 613AF



F = Specific Device Code M = Date Code

PIN ASSIGNMENTS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

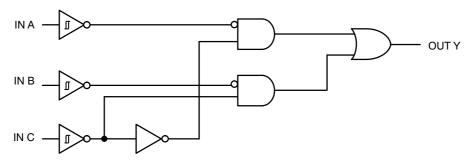


Figure 1. Function Diagram

PIN ASSIGNMENT

1	IN B
2	GND
3	IN A
4	OUT Y
5	V _{CC}
6	IN C

FUNCTION TABLE*

	Input				
А	В	С	Υ		
L	L	L	L		
L	L	Н	L		
L	Н	L	Н		
L	Н	Н	L		
Н	L	L	L		
Н	L	Н	Н		
Н	Н	L	Н		
Н	Н	Н	Н		

^{*}To select a logic function, please refer to "Logic Configurations section".

LOGIC CONFIGURATIONS

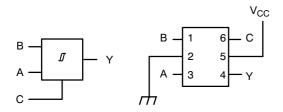


Figure 2. 2-Input MUX

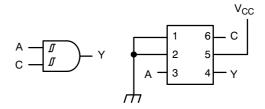
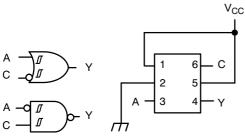


Figure 3. 2-Input AND (When B = "L")

 V_{CC}



(When B = "H")



Figure 5. 2-Input AND with Input C Inverted (When A = "L")

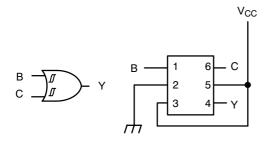


Figure 6. 2-Input OR (When A ="H")

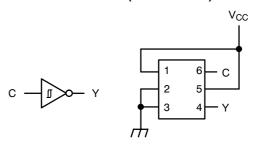


Figure 7. Inverter (When A = "L" and B =

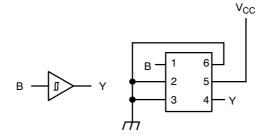


Figure 8. Buffer (When A = C = "L")

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage		-0.5 to +7.0	V
V _{OUT}	DC Output Voltage		-0.5 to +7.0	V
I _{IK}	DC Input Diode Current V _{IN} < G	ND	-50	mA
I _{OK}	DC Output Diode Current V _{OUT} < G	ND	-50	mA
ΙO	DC Output Source/Sink Current		±50	mA
I _{CC}	DC Supply Current Per Supply Pin		± 100	mA
I _{GND}	DC Ground Current per Ground Pin		± 100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
T_J	Junction Temperature Under Bias		150	°C
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating Oxygen Index: 28 to 34		UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Model (Note Machine Model (Note Charged Device Model (Note	3)	>2000 >200 N/A	V
I _{LATCHUP}	Latchup Performance Above V _{CC} and Below GND at 125°C (Note 5)		±500	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

- Tested to EIA/JESD22-A114-A.
 Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.
- Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	Positive DC Supply Voltage	1.65	5.5	V
V _{IN}	Digital Input Voltage	0	5.5	V
V _{OUT}	Output Voltage	0	5.5	V
T _A	Operating Free-Air Temperature	-55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate $ \begin{array}{c} V_{CC} = 2.5 \ V \ \pm \ 0.2 \ V \\ V_{CC} = 3.3 \ V \ \pm \ 0.3 \ V \\ V_{CC} = 5.0 \ V \ \pm \ 0.5 \ V \\ \end{array} $	0 0 0	No Limit No Limit No Limit	nS/V

DC ELECTRICAL CHARACTERISTICS

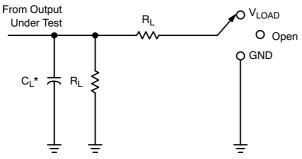
			v _{cc}	-	Γ _A = 25°	С	T _A ≤	+85°C		55°C to 5°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V_{T+}	Positive		1.65	0.79		1.16		1.16		1.16	V
	Threshold Voltage		2.3	1.11		1.56		1.56		1.56	
			3.0	1.5		1.87		1.87		1.87	
			4.5	2.16		2.74		2.74		2.74	
			5.5	2.61		3.33		3.33		3.33	
V _{T-}	Negative		1.65	0.35		0.62	0.35		0.35		V
	Threshold Voltage		2.3	0.58		0.87	0.58		0.58		
	Voltage		3.0	0.84		1.19	0.84		0.84		
			4.5	1.41		1.9	1.41		1.41		
			5.5	1.78		2.29	1.78		1.78		
V _H	Hysteresis		1.65	0.30		0.62	0.30	0.62	0.30	0.62	V
	Voltage		2.3	0.40		0.8	0.40	0.8	0.40	0.8	
			3.0	0.53		0.87	0.53	0.87	0.53	0.87	
			4.5	0.71		1.04	0.71	1.04	0.71	1.04	
			5.5	0.8		1.2	0.8	1.2	0.8	1.2	
V _{OH}	Minimum High-Level	$V_{IN} = V_{T-MIN} \text{ or } V_{T+MAX}$ $I_{OH} = -50 \mu\text{A}$	1.65 - 5.5	V _{CC} - 0.1			V _{CC} - 0.1		V _{CC} - 0.1		V
	Output Voltage	$V_{IN} = V_{T-MIN}$ or V_{T+MAX}									
		I _{OH} = -4 mA	1.65	1.2			1.2		1.2		
		I _{OH} = -8 mA	2.3	1.9			1.9		1.9		
		I _{OH} = -16 mA	3.0	2.4			2.4		2.4		
		I _{OH} = -24 mA	3.0	2.3			2.3		2.3		
		I _{OH} = -32 mA	4.5	3.8			3.8		3.8		
V _{OL}	Maximum Low-Level	$V_{IN} = V_{T-MIN} \text{ or } V_{T+MAX}$ $I_{OL} = 50 \mu\text{A}$	1.65 - 5.5			0.1		0.1		0.1	V
	Output Voltage	$V_{IN} = V_{T-MIN}$ or V_{T+MAX}									
		I _{OL} = 4 mA	1.65			0.45		0.45		0.45	
		I _{OL} = 8 mA	2.3			0.3		0.3		0.3	
		I _{OL} = 16 mA	3.0			0.4		0.4		0.4	
		I _{OL} = 24 mA	3.0			0.55		0.55		0.55	
		I _{OL} = 32 mA	4.5			0.55		0.55		0.55	
I _{IN}	Input Leakage Current	0 ≤ V _{IN} ≤ 5.5 V	0 to 5.5			±0.1		±1.0		±1.0	μΑ
I _{CC}	Quiescent Supply Current	$0 \le V_{IN} \le V_{CC}$	5.5			1.0		10		10	μΑ

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

				٦	Γ _A = 25°(T _A ≤	+85°C		-55°C 25°C	
Symbol	Parameter	V _{CC} (V)	Test Condition	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLH} ,	Propagation Delay,	1.65 - 1.95		3.2	8.6	14.4	3.2	14.4	3.2	14.4	ns
t _{PHL}	Any Input to Output Y (See Test Circuit)	2.3 - 2.7		2.0	5.1	8.3	2.0	8.3	2.0	8.3	
		3.0 - 3.6		1.5	3.9	6.3	1.5	6.3	1.5	6.3	
		4.5 - 5.5		1.1	3.3	5.1	1.1	5.1	1.1	5.1	
C _{IN}	Input Capacitance				3.5						pF
C _{PD}	Power Dissipation Capacitance (Note 6)	5.0	f = 10 MHz		22						pF

^{6.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption: P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

TEST CIRCUIT AND VOLTAGE WAVEFORMS



Test	S 1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V_{LOAD}
t _{PHZ} /t _{PZH}	GND

Figure 9. Load Circuit

	Inp	outs					
V _{CC}	VI	t _r /t _f	V_{M}	V _{LOAD}	CL	R_{L}	V_Δ
1.8 V ± 0.15 V	V _{CC}	≤ 2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	1 kΩ	0.15 V
2.5 V ± 0.2 V	V _{CC}	≤ 2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
3.3 V ± 0.3 V	3 V	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5.5 V ± 0.5 V	V _{CC}	≤ 2.5 ns	V _{CC} /2	2 x V _{CC}	50 pF	500 Ω	0.3 V

^{*}C_L includes probes and jig capacitance.

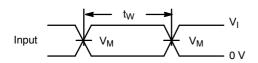


Figure 10. Voltage Waveforms Pulse Duration

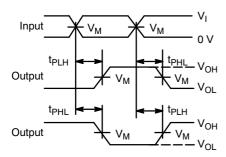


Figure 12. Voltage Waveforms Propagation Delay Times Inverting and Noninverting Outputs

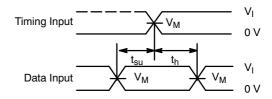


Figure 11. Voltage Waveforms Setup and Hold Times

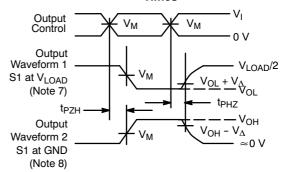


Figure 13. Voltage Waveforms Enable and Disable Times Low- and High-Level Enabling

- 7. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
- 8. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control
- 9. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$.
- 10. The outputs are measured one at a time, with one transition per measurement.
- 11. All parameters are waveforms are not applicable to all devices.

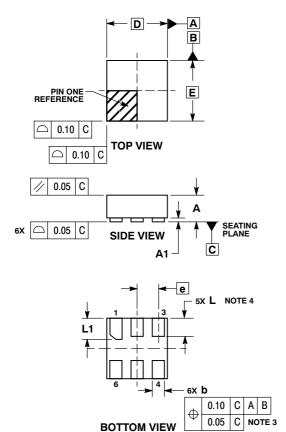
ORDERING INFORMATION

Device	Package	Shipping [†]
NLX1G97AMX1TCG	ULLGA6 - 0.5P (Pb-Free)	3000 / Tape & Reel
NLX1G97BMX1TCG	ULLGA6 - 0.4P (Pb-Free)	3000 / Tape & Reel
NLX1G97CMX1TCG	ULLGA6 - 0.35P (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

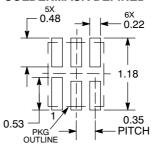
ULLGA6 1.0x1.0, 0.35P CASE 613AD-01 ISSUE A



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.
 4. A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALLOWED. PACKAGE IS ALLOWED.

_	MILLIMETERS				
DIM	MIN	MAX			
Α	-	0.40			
A1	0.00	0.05			
b	0.12	0.22			
D	1.00	BSC			
E	1.00	BSC			
е	0.35 BSC				
L	0.25	0.35			
L1	0.30	0.40			

MOUNTING FOOTPRINT SOLDERMASK DEFINED*

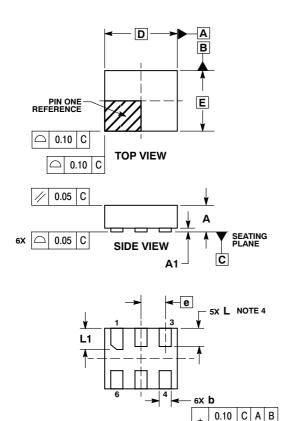


DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

ULLGA6 1.2x1.0, 0.4P CASE 613AE-01 ISSUE A



BOTTOM VIEW

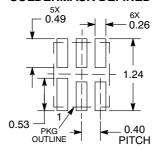
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0.05 C NOTE 3

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
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	MILLIMETERS			
DIM	MIN	MAX		
Α		0.40		
A1	0.00	0.05		
b	0.15	0.25		
D	1.20	BSC		
Е	1.00 BSC			
е	0.40 BSC			
L	0.25	0.35		
L1	0.35	0.45		

MOUNTING FOOTPRINT SOLDERMASK DEFINED*

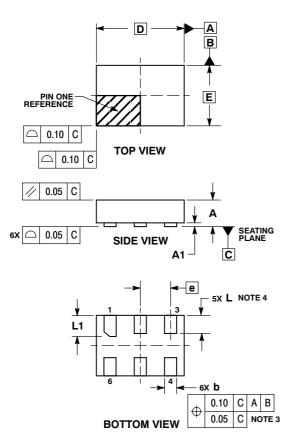


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PACKAGE DIMENSIONS

ULLGA6 1.45x1.0, 0.5P CASE 613AF-01 **ISSUE A**

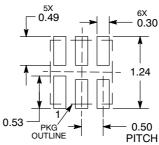


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- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
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- A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALLOWED.

_	MILLIMETERS				
DIM	MIN	MAX			
Α	-	0.40			
A1	0.00	0.05			
b	0.15	0.25			
D	1.45	BSC			
E	1.00	BSC			
е	0.50 BSC				
L	0.25	0.35			
L1	0.30	0.40			

MOUNTING FOOTPRINT SOLDERMASK DEFINED*



DIMENSIONS: MILLIMETERS

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